

High efficiency $\text{Mg}_2(\text{Si}, \text{Sn})$ based thermoelectric materials: scale-up synthesis, functional homogeneity, and thermal stability

Nader Farahi *, Christian Stiewe, D. Y. Nhi Truong, Johannes de Boor, and Eckhard Müller

^aInstitute of Materials Research, German Aerospace Center (DLR), D-51170 Köln, Germany, nfarahi@uwaterloo.ca

^bInstitute of Inorganic and Analytical Chemistry, Justus Liebig University Gießen, D-35392 Gießen, Germany

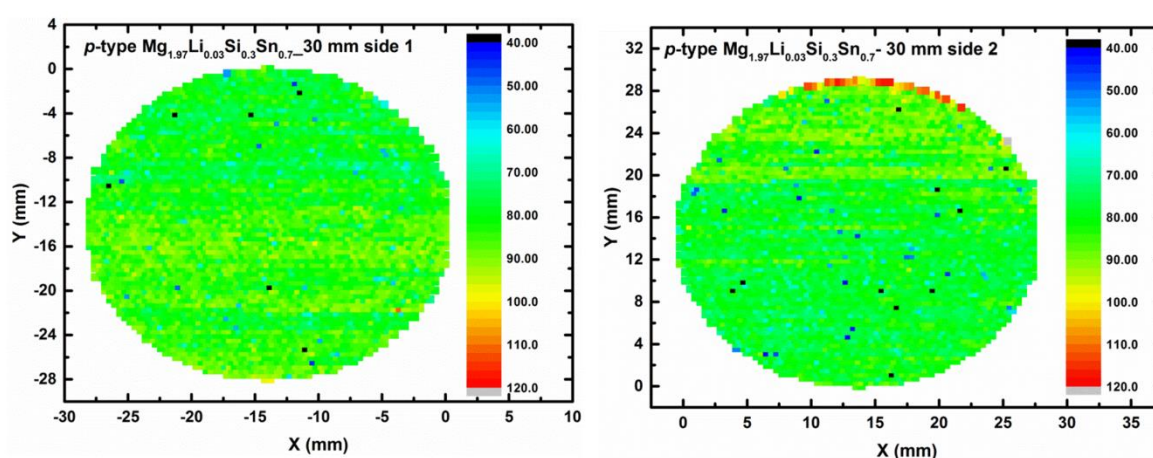


Fig. S1. Surface Seebeck scans of both base faces of the Ø30 mm $\text{Mg}_{1.97}\text{Li}_{0.03}\text{Si}_{0.3}\text{Sn}_{0.7}$ pellet (error 5%).

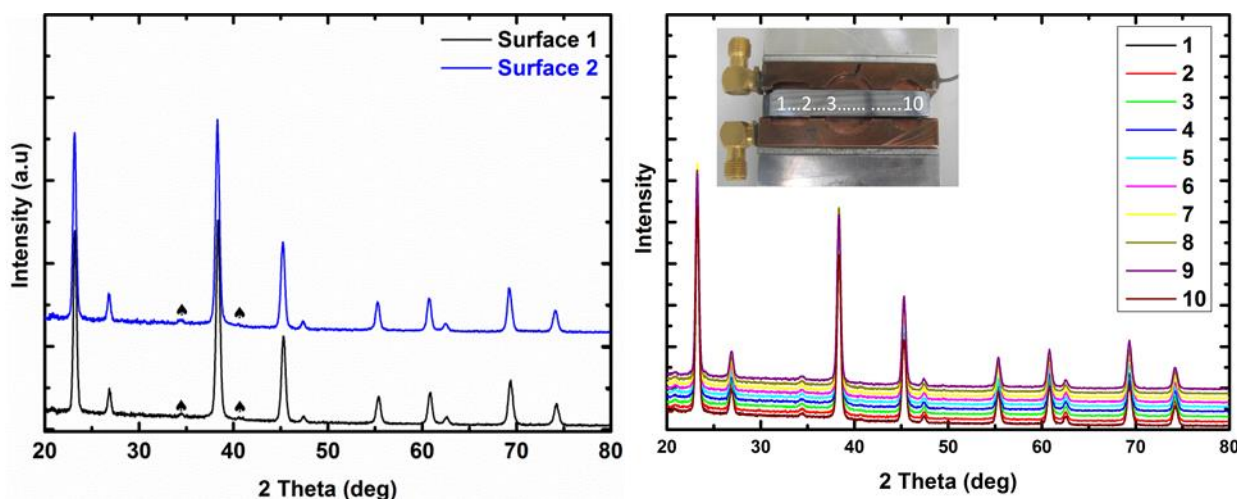


Fig. S2. X-ray diffraction patterns on the both surfaces and the cross section (left) and ten different points on cross section (right) of the Ø50 mm $\text{Mg}_2\text{Si}_{0.3}\text{Sn}_{0.675}\text{Bi}_{0.025}$ sample.

Table S1. Density and calculated specific heat of four samples extracted from the Ø50 mm pellet.

Sample	Density ($\text{g}\cdot\text{cm}^{-3}$) (Archimedes method)	Specific Heat ($\text{J}\cdot\text{g}^{-1}\cdot\text{K}^{-1}$) (Dulong-Petit approximation)
I	3.11 (> 98% theoretical density)	0.514
II	3.14 (> 98% theoretical density)	0.514
III	3.13 (> 98% theoretical density)	0.514
IV	3.14 (> 98% theoretical density)	0.514

Table S2. Density and calculated specific heat of three samples extracted from the Ø70 mm pellet.

Sample	Density ($\text{g}\cdot\text{cm}^{-3}$) (Archimedes method)	Specific Heat ($\text{J}\cdot\text{g}^{-1}\cdot\text{K}^{-1}$) (Dulong-Petit approximation)
I	3.15 (> 98% theoretical density)	0.514
II	3.14 (> 98% theoretical density)	0.514
III	3.13 (> 98% theoretical density)	0.514

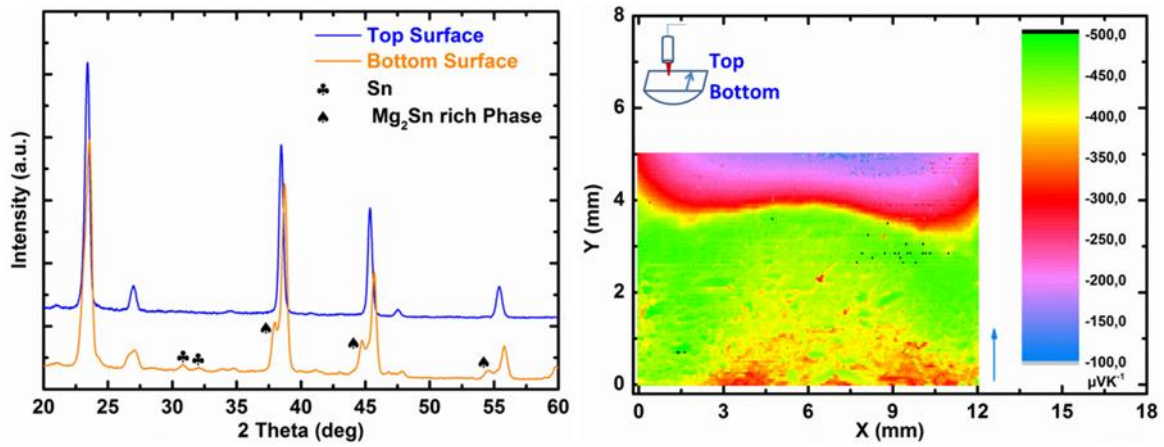


Fig. S3. X-ray diffraction patterns on the top and bottom surfaces (left) and surface Seebeck scan on cross section (right) of the $\text{Mg}_2\text{Si}_{0.3}\text{Sn}_{0.675}\text{Bi}_{0.025}$ sample with current passing through the sample.

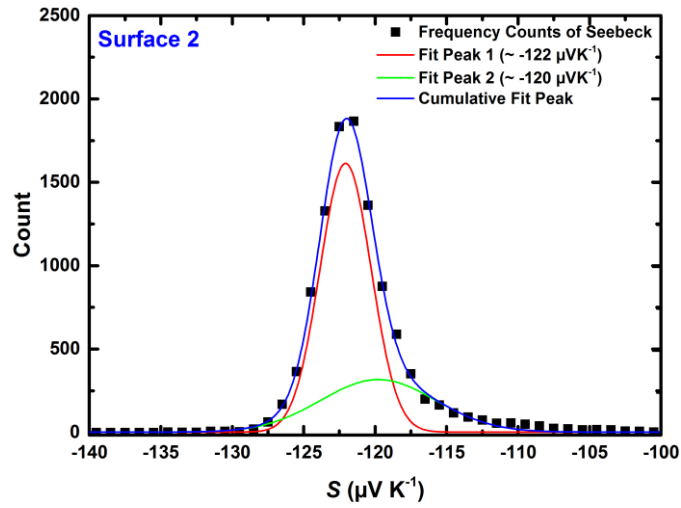


Fig. S4. Frequency count of surface Seebeck scan performed on one of the two surfaces of the $\text{Ø}50 \text{ mm Mg}_2\text{Si}_{0.3}\text{Sn}_{0.675}\text{Bi}_{0.025}$ sample.

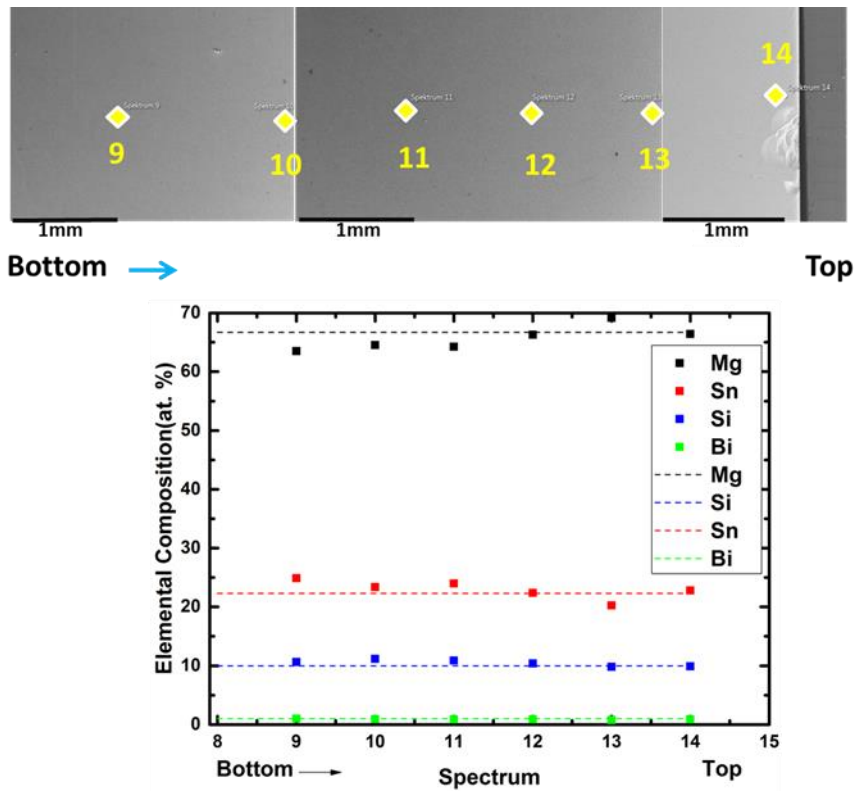


Fig. S5. SEM image (top) together with EDX analysis (bottom) along the cross section of the $\text{Ø}50 \text{ mm Mg}_2\text{Si}_{0.3}\text{Sn}_{0.675}\text{Bi}_{0.025}$ sample. The dash lines represent the nominal compositions.

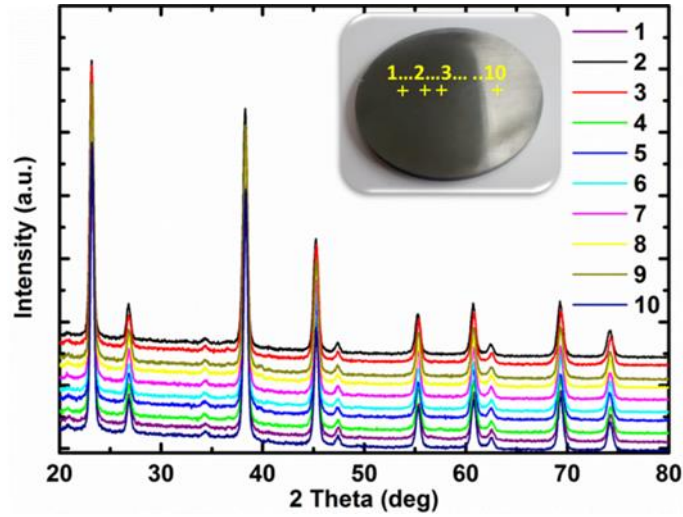


Fig. S6. XRD patterns on the surface of the $\varnothing 70$ mm $\text{Mg}_2\text{Si}_{0.3}\text{Sn}_{0.675}\text{Bi}_{0.025}$ sample.

Table S3. Thermoelectric properties of three samples extracted from the $\varnothing 70$ mm pellet before and after heat treatment at ~ 773 K.

Thermoelectric properties	1 (168 h)	2 (336 h)	3 (720 h)
$\sigma/(\Omega^{-1}\text{cm}^{-1})^*$	1051/1049	1025/1000	1020/997
$S/(\mu\text{V K}^{-1})^*$	-198/-201	-198/-201	-198/-209

*properties compared at 773 K, before annealing/ after annealing.

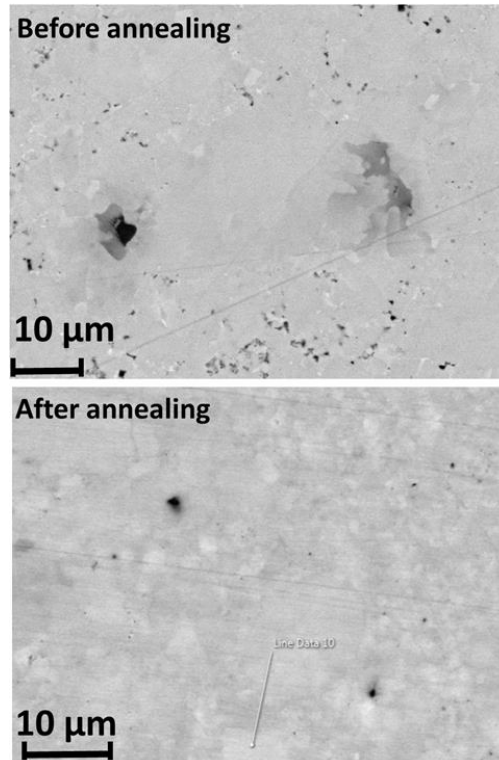


Fig. S7. SEM image of the sample (top) before and (bottom) after heat treatment at 723 K for 720 hours.